

David H Meyer

List of Publications by Year in descending order

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Version: 2024-02-01

17

papers

476

citations

1307594

7

h-index

1125743

13

g-index

17

all docs

17

docs citations

17

times ranked

296

citing authors

#	ARTICLE		IF	CITATIONS
1	Waveguide-Coupled Rydberg Spectrum Analyzer from 0 to 20 GHz. Physical Review Applied, 2021, 15, .	3.8	82	
2	Optimal atomic quantum sensing using electromagnetically-induced-transparency readout. Physical Review A, 2021, 104, .	2.5	21	
3	Rydberg Vapor EIT Sensing Performance. , 2021, , .	0		
4	Assessment of Rydberg atoms for wideband electric field sensing. Journal of Physics B: Atomic, Molecular and Optical Physics, 2020, 53, 034001.	1.5	74	
5	Receiving Electric Fields with a Rydberg Quantum Sensor. , 2020, , .	0		
6	Spin-Wave Multiplexed Atom-Cavity Electrodynamics. Physical Review Letters, 2019, 123, 263601.	7.8	9	
7	Spatial multiplexing in a cavity-enhanced quantum memory. , 2019, , .	0		
8	Increased atom-cavity coupling and stability using a parabolic ring cavity. Journal of Physics B: Atomic, Molecular and Optical Physics, 2018, 51, 195002.	1.5	6	
9	Quantum-Limited Atomic Receiver in the Electrically Small Regime. Physical Review Letters, 2018, 121, 110502.	7.8	91	
10	Digital communication with Rydberg atoms and amplitude-modulated microwave fields. Applied Physics Letters, 2018, 112, .	3.3	139	
11	Twists in nonlinear magneto-optic rotation with cold atoms. Optics Express, 2017, 25, 16392.	3.4	2	
12	Nonlinear polarization spectroscopy of a Rydberg state for laser stabilization. Applied Optics, 2017, 56, B92.	2.1	7	
13	Microwave electric field sensing with Rydberg atoms. , 2016, , .	1		
14	Growth and temperature dependent photoluminescence of InGaAs quantum dot chains. Applied Surface Science, 2014, 296, 8-14.	6.1	4	
15	Long-lived electron spins in a modulation doped (100) GaAs quantum well. Journal of Applied Physics, 2012, 112, . Universal scheme for measuring the electron $\langle mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" altimg="si1.gif" display="inline" overflow="scroll" \rangle \langle mml:msub \rangle \langle mml:mrow \rangle \langle mml:mi \rangle T \langle /mml:mi \rangle \langle /mml:mrow \rangle \times \langle mml:mrow \rangle \langle mml:mn \rangle 1 \langle /mml:mn \rangle \langle /mml:mrow \rangle \times \langle mml:mrow \rangle \langle mml:mi \rangle n \langle /mml:mi \rangle \langle /mml:math \rangle - GaAs sample. Solid State Communications, 2012, 149, 1.$	2.5	2	
16	in semiconductors and application to a lightly-doped $\langle mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" altimg="si2.gif" display="inline" overflow="scroll" \rangle \langle mml:mi \rangle n \langle /mml:mi \rangle \langle /mml:math \rangle - GaAs sample. Solid State Communications, 2012, 149, 1.$	1.9	1	
17	Ionic Specificity in pH Regulated Charged Interfaces: Fe ³⁺ versus La ³⁺ . Langmuir, 2011, 27, 11917-11924.	3.5	37	